# imall

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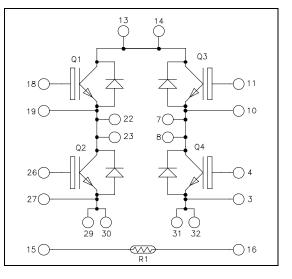
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Full bridge High speed Trench + Field Stop IGBT4 Power Module



# Proprovence 28 27 26 25 23 22 20 19 18 29 87 26 25 23 22 20 19 18 29 87 23 22 20 19 18 30 15 15 15 15 15 15 82 13 13 <t

All multiple inputs and outputs must be shorted together ; Example: 13/14 ; 29/30 ; 22/23 ...

#### $V_{CES} = 650V$ $I_{C} = 50A$ @ Tc = 60°C

#### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### Features

#### • High speed Trench + Field Stop IGBT 4 Technology

- Low voltage drop
- Low leakage current
- Low switching losses
- Very low stray inductance
- Internal thermistor for temperature monitoring

#### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS compliant

#### All ratings (a) $T_i = 25^{\circ}C$ unless otherwise specified

#### Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Voltage		650	V
т	Continuous Collector Current $\frac{T_C}{T_C}$	= 25°C	70	
I <sub>C</sub>	$T_{\rm C} = 60^{\circ}{\rm C}$		50	Α
I <sub>CM</sub>	Pulsed Collector Current T <sub>C</sub>	= 25°C	140	
V <sub>GE</sub>	Gate – Emitter Voltage		±20	V
P <sub>D</sub>	Power Dissipation		175	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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#### Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$				50	μA
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_C = 50A$	$T_j = 25^{\circ}C$	1.4	1.85	2.3	V
V <sub>CE(sat)</sub>			$T_{j} = 150^{\circ}C$		2.2		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 0.8 \text{ mA}$		4.2	5.1	5.6	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				150	nA

#### Dynamic Characteristics (per IGBT)

Symbol	<i>Characteristic</i>	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			3100		
C <sub>oes</sub>	Output Capacitance				116		pF
Cres	Reverse Transfer Capacitance	f = 1MHz			90		
Q <sub>G</sub>	Gate charge	$V_{GE} = 15V, I_C = 50A$ $V_{CE} = 480V$			315		nC
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switc	hing (25°C)		19		
T <sub>r</sub>	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 400V$			33		ns
T <sub>d(off)</sub>	Turn-off Delay Time	$I_{\rm C} = 50 \text{A}$			197		115
T <sub>f</sub>	Fall Time	$R_G = 7\Omega$			21		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 400V$ $I_C = 50A$ $R_G = 7\Omega$			19		
T <sub>r</sub>	Rise Time				29		
T <sub>d(off)</sub>	Turn-off Delay Time				227		ns
T <sub>f</sub>	Fall Time				22		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 400V$	$T_{j} = 150^{\circ}C$		1.2		mI
E <sub>off</sub>	Turn off Energy	$ I_C = 50A  R_G = 7\Omega $ $ T_j = 150^{\circ}C $			1		mJ
I <sub>sc</sub>	Short Circuit data	$V_{GE} \le 15V$ ; $V_{Bus} = 400V$ $t_p \le 5\mu s$ ; $T_j = 150^{\circ}C$			350		А
R <sub>thJC</sub>	Junction to Case Thermal Resistance	ction to Case Thermal Resistance				0.85	°C/W

#### Diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage					650	V
I <sub>RM</sub>	Reverse Leakage Current	$V_R = 650V$				50	μΑ
I <sub>F</sub>	DC Forward Current		$Tc = 25^{\circ}C$		50		А
V <sub>F</sub>	Diode Forward Voltage	$I_{\rm F} = 50 A$ $V_{\rm GE} = 0 V$	$T_i = 25^{\circ}C$		1.6	2	V
v ⊧			$T_{i} = 150^{\circ}C$		1.5		v
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 50A$ $V_R = 300V$ $di/dt = 1800A/\mu s$	$T_j = 25^{\circ}C$		100		ns
۲r	Reverse Recovery Time		$T_{j} = 150^{\circ}C$		150		115
0	Reverse Recovery Charge		$T_j = 25^{\circ}C$		2.6		μC
Q <sub>rr</sub>	Keverse Kecovery Charge		$T_{j} = 150^{\circ}C$		5.4		μΟ
E <sub>rr</sub>		$T_j = 25^{\circ}C$		0.6		mJ	
L	Reverse Recovery Energy		$T_{j} = 150^{\circ}C$		1.2		1115
R <sub>thJC</sub>	Junction to Case Thermal Resistance					1.42	°C/W

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#### Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

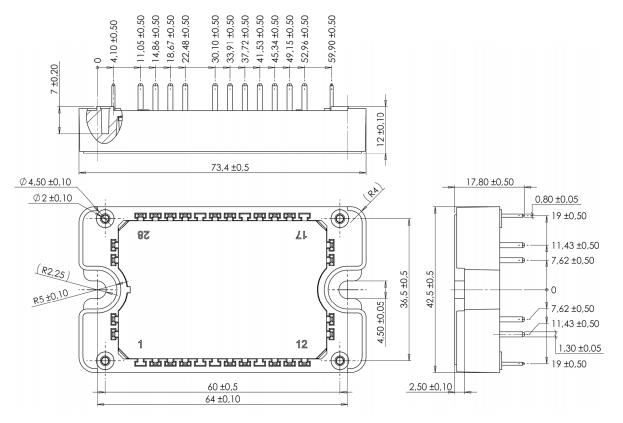
Symbol	Characteristic		Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		T <sub>C</sub> =100°C		4		%
	מ					

 $R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$  T: Thermistor temperature R<sub>T</sub>: Thermistor value at T

#### Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz					V
T <sub>J</sub>	Operating junction temperature range				175	
T <sub>JOP</sub>	Recommended junction temperature under switching conditions			-40	T <sub>J</sub> max -25	°C
T <sub>STG</sub>	Storage Temperature Range			-40	125	C
T <sub>C</sub>	Operating Case Temperature				125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

#### Package outline (dimensions in mm)



See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

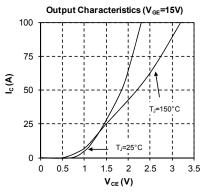
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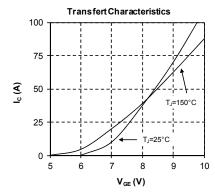
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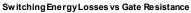


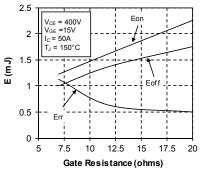
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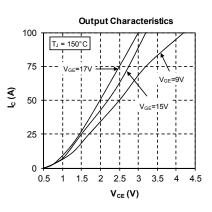
#### Typical performance curve



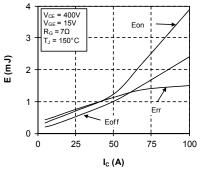


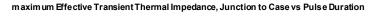


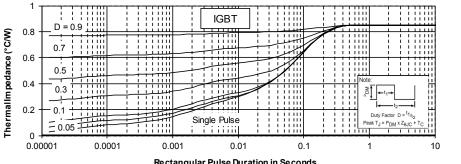












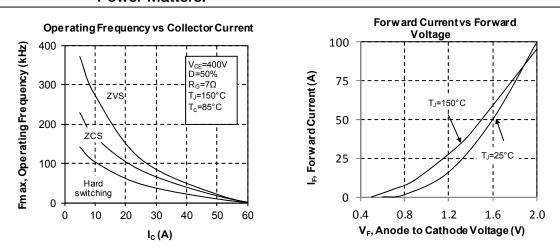


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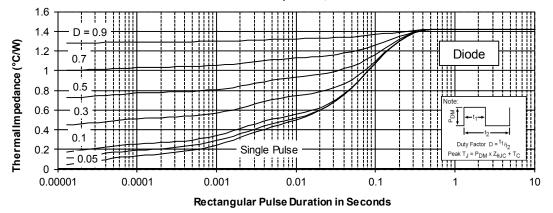
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maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



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